

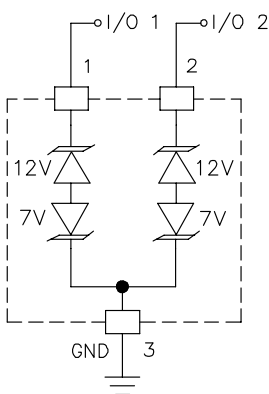
Description

The ASM712H is designed for asymmetrical (12V to -7V) protection in multi-point data transmission application, The ASM712H replace four discrete components by integrating two 12V and two 7V TVS diodes in a single package. The ASM712H complies with the IEC 61000-4-2 (ESD) with $\pm 30\text{kV}$ air and $\pm 30\text{kV}$ contact discharge. It is assembled into a lead-free SOT-23 package. It is designed to protect components which are connected to data and transmission lines from voltage surges.

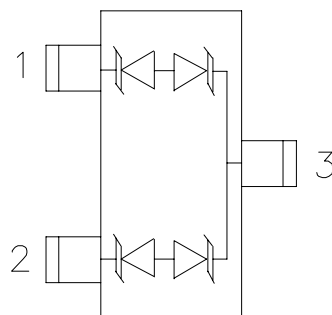
Features

- Ultra low leakage: nA level
- Operating voltage: 7V or 12V
- Low clamping voltage
- Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test
 - Air discharge: $\pm 30\text{kV}$
 - Contact discharge: $\pm 30\text{kV}$
 - IEC61000-4-5 (Lightning)
 - 30A for 12V & 38A for 7V (8/20 μs)
- RoHS Compliant

Dimensions and Pin Configuration



Circuit Schematic



Pin Schematic

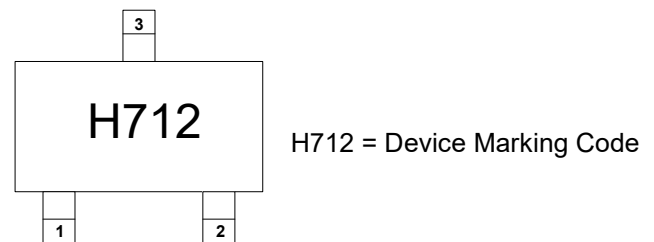
Mechanical Characteristics

- Package: SOT-23
- Lead Finish: Matte Tin
- Case Material: "Green" Molding Compound.
- Terminal Connections: See Diagram Below
- Marking Information: See Below

Applications

- Wireless System
- Networks
- Portable Instrumentation
- RS485 Ports

Marking Information



Ordering Information

Part Number	Packaging	Reel Size
ASM712H	3000/Tape & Reel	7 inch

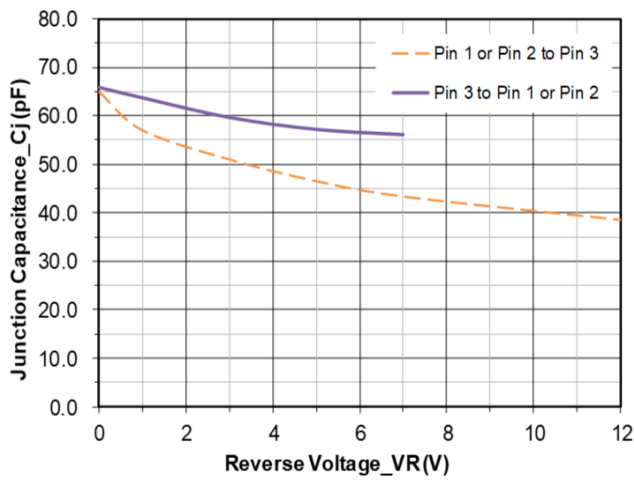
Absolute Maximum Ratings (T_A=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20μs)	Ppk	600-1000	W
Peak Pulse Current (tp = 8/20μs), Pin 1 or 2 to Pin 3	Ipp	30	A
Peak Pulse Current (tp = 8/20μs), Pin 3 to Pin 1 or 2		38	
ESD per IEC 61000-4-2 (Air)	VESD	±30	kV
ESD per IEC 61000-4-2 (Contact)		±30	
Operating Temperature Range	TJ	-55 to +125	°C
Storage Temperature Range	Tstg	-55 to +150	°C

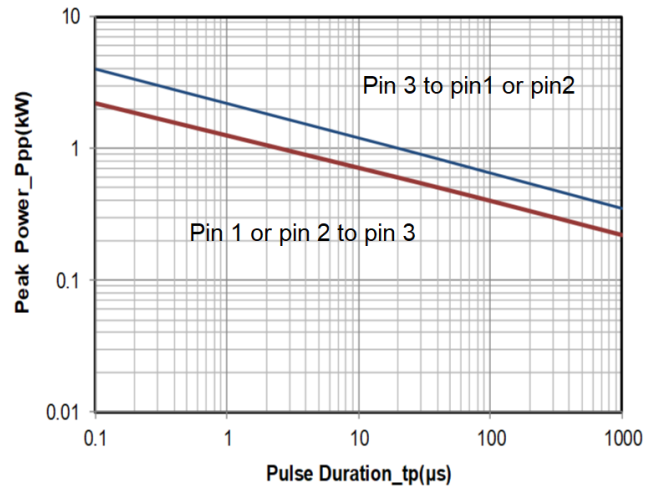
Electrical Characteristics (T_A=25°C unless otherwise specified)

Parameter	Symbol	Pin 1 to 3 and 2 to 3 (12V TVS)			Pin 3 to 1 and 3 to 2 (7V TVS)			Unit	Test Condition
		Min	Typ	Max	Min	Typ	Max		
Reverse Working Voltage	VRWM			12			7	V	
Breakdown Voltage	VBR	13.3			7.5			V	IT = 1mA
Reverse Leakage Current	IR			0.5			0.5	μA	VR = VRWM
Clamping Voltage	VC			19			11	V	I _{PP} = 1A (8 x 20μs pulse)
Clamping Voltage	VC			26			NA	V	I _{PP} = 30A (8 x 20μs pulse)
Clamping Voltage	VC			NA			17	V	I _{PP} = 38A (8 x 20μs pulse)
Junction Capacitance	CJ			75			75	pF	VR = 0V, f = 1MHz
Junction Capacitance	CJ		38			55		pF	VR = VRWM, f = 1MHz

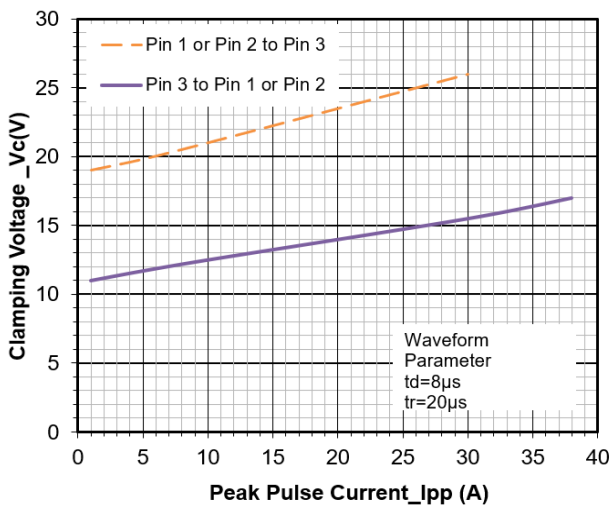
Typical Performance Characteristics ($T_A=25^\circ\text{C}$ unless otherwise Specified)



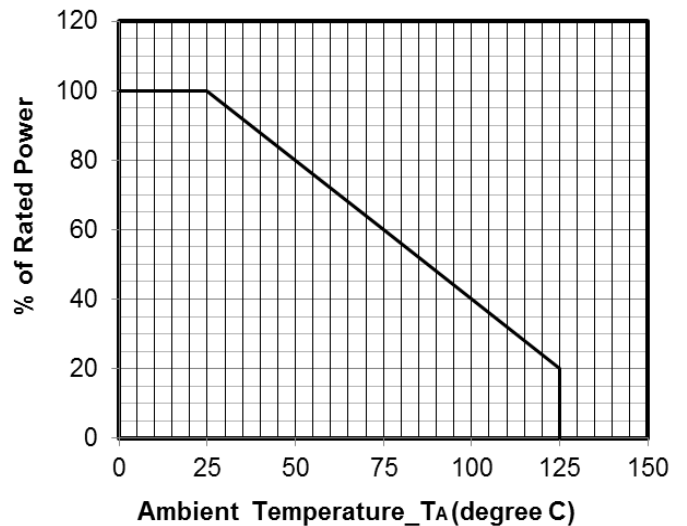
Junction Capacitance vs. Reverse Voltage



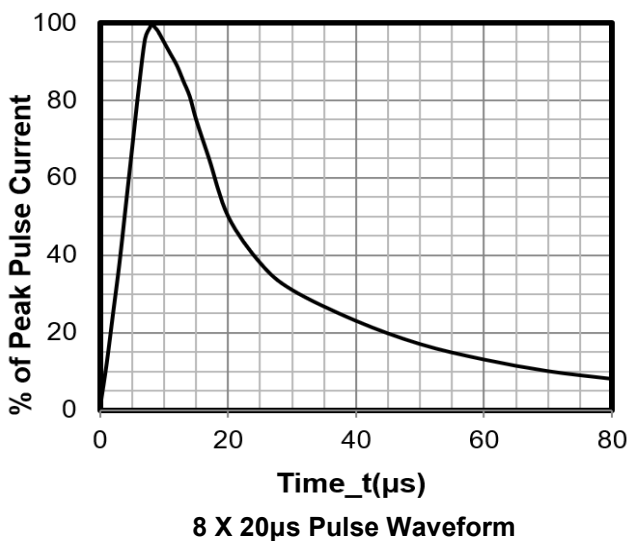
Peak Pulse Power vs. Pulse Time



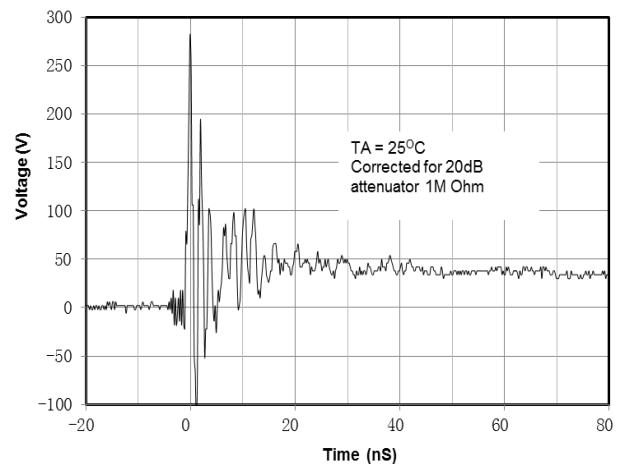
Clamping Voltage vs. Peak Pulse Current



Power Derating Curve



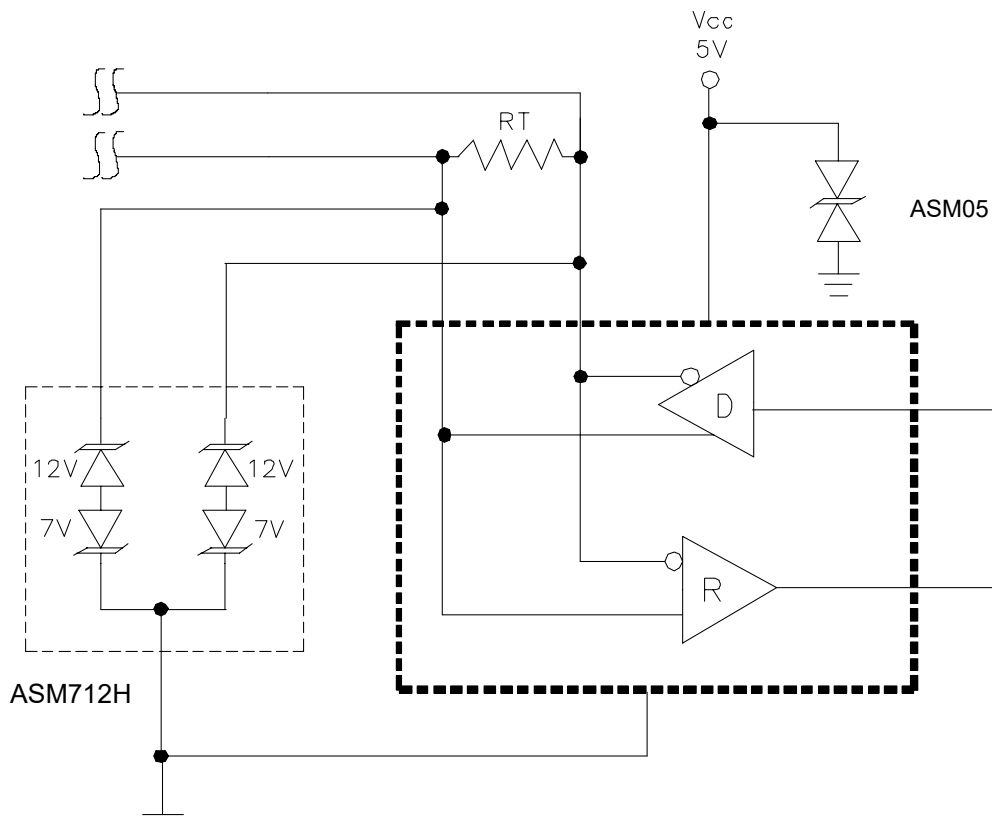
8 X 20 μs Pulse Waveform

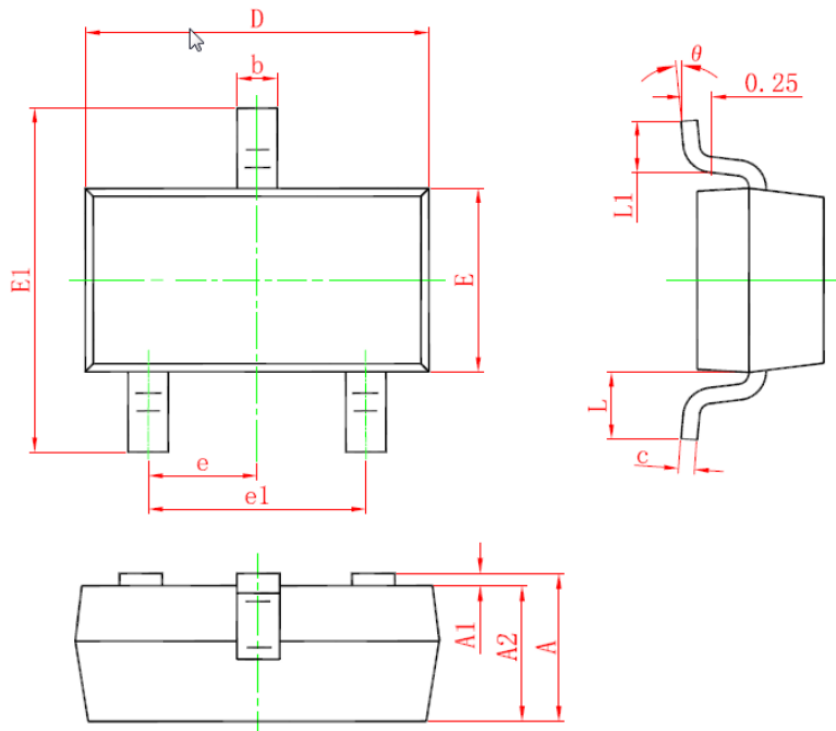


**ESD Clamping Voltage
8 kV Contact per IEC61000-4-2**

ASM712H on RS-485 Data Lines Application

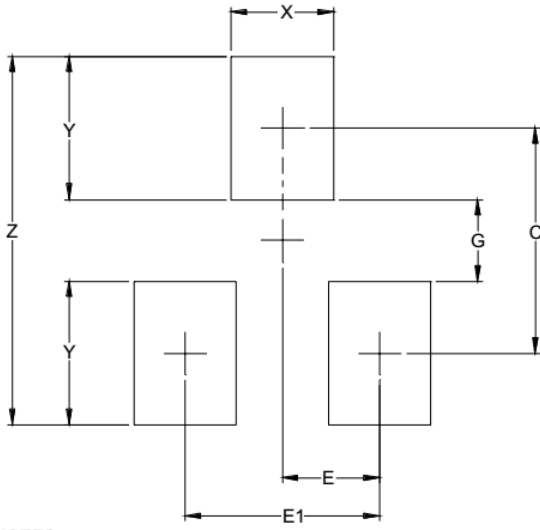
EIA RS-485 specifies a $\pm 7V$ ground difference between devices on the bus. This permits the bus voltage to range from +12V (5V + 7V) to -7V (0 - 7V). The ASM712H is designed to protect two RS-485 data lines in extended common mode applications. The ASM712H may be used to protect devices from transient voltages resulting from ESD, EFT, and lightning. The device is designed with asymmetrical operating voltages for optimum protection. The TVS diodes at pins 1 and 2 have a working voltage of 12volts. These pins are connected to the differential data line pairs. The TVS diodes at pin 3 have a working voltage of 7volts. Pin 3 is connected to ground. The internal TVS diodes of the ASM712H will protect the transceiver input from positive transient voltage spikes greater than 12V and negative spikes greater than 7V.



SOT-23 Package Outline Drawing


SYM	DIMENSIONS					
	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.90	--	1.15	0.035	--	0.045
A1	0.00	--	0.10	0.000	--	0.004
A2	0.90	--	1.05	0.035	--	0.041
b	0.30	--	0.50	0.012	--	0.020
c	0.08	--	0.15	0.003	--	0.006
D	2.80	--	3.00	0.110	--	0.118
E	1.20	--	1.40	0.047	--	0.055
E1	2.25	--	2.55	0.089		0.100
e	0.95TYP			0.037TYP		
e1	1.80	--	2.00	0.071	--	0.079
L	0.55REF			0.022REF		
L1	0.30	--	0.50	0.012	--	0.020
θ	0°	--	8°	0°	--	8°

Suggested Land Pattern



SYM	DIMENSIONS	
	INCHES	MILLIMETERS
C	0.087	(2.20)
E	0.037	0.95
E1	0.075	1.90
G	0.031	0.80
X	0.039	1.00
Y	0.055	1.40
Z	0.141	3.60

Contact Information

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